Revision 0.94

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

General Product Information

Product	Application
Tunable 760 nm DFB Laser	Spectroscopy
with hermetic 14 Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	Oxygen Detection
with integrated Beam Collimation	

Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	T _C	°C	-40		85
Operational Temperature at Laser Chip	T _{LD}	°C	10		50
Forward Current	I _F	mA			130
Reverse Voltage	V _R	V			2
Output Power	P _{opt}	mW			50
TEC Current	I _{TEC}	А			1.1
TEC Voltage	V _{TEC}	V			2.8

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _{case}	°C	-20		65
Operational Temperature at Laser Chip	T _{LD}	°C	10		35
Forward Current	I _F	mA			120
Output Power	P _{opt}	mW	10		40

Characteristics at T_{LD} = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	759.9	760.9	761.9
Target Wavelength	λ_T	nm		760.9	
Linewidth (FWHM)	$\Delta\lambda$	MHz		2	
Mode-hop free Tuning Range	$\Delta\lambda_{tune}$	pm	40		
Sidemode Supression Ratio	SMSR	dB	30	50	

eagleyard Photonics GmbH Rudower Chaussee 29 12489 Berlin GERMANY www.eagleyard.com info@eagleyard.com fon +49.30.6392 4520



2020-11-11

eaalevard



Measurement Conditions / Comments Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Measurement Conditions / Comments

measured by integrated thermistor

Measurement Conditions / Comments

reached within T_{LD} = 10° and 35° C at 40 mW
$P_{opt} = 40 \text{ mW}$
at target wawevelength
$P_{opt} = 40 \text{ mW}$

This data sheet is subject to change without notice. © eagleyard Photonics

Revision 0.94

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

Characteristics at I _{LD} = 25° C at BOL							
Parameter	Symbol	Unit	min	typ	max		
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06			
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.002			
Laser Current @ $P_{opt} = 40 \text{ mW}$	I _{LD}	mA			120		
Slope Efficiency	η	W / A	0.6	0.8	1.3		
Threshold Current	I _{th}	mA			70		
Divergence parallel (FWHM)	$\Theta_{ }$	0		0.1			
Divergence perpendicular (FWHM)	Θ_{\perp}	0		0.1			
Beam Diameter horizontal	d	mm		1.0	1.2		
Beam Diameter vertical	d_\perp	mm		0.8	1.2		
Degree of Polarization	DOP	%		90			

Measurement Conditions / Comments

parallel to the base plate of the housing (see p. 3) perpendicular to base plate of the housing (see p. 3) parallel to the base plate of the housing (see p. 3) perpendicular to base plate of the housing (see p. 3) $P_{opt} = 40$ mW; E field perpendicular to base plate

Monitor Diode

Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{opt}	µA/mW	3		60

Thermoelectric Cooler

Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.4	
Voltage	U _{TEC}	V		1.3	
Power Dissipation (total loss at case)	P _{loss}	W		0.4	
Temperature Difference	ΔΤ	К			50

Thermistor (Standard NTC Type)

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	А			1.1293 x 10) ⁻³
Steinhart & Hart Coefficient B	В			2.3410 x 10) -4
Steinhart & Hart Coefficient C	С			8.7755 x 10) -8

eagleyard Photonics GmbH Rudower Chaussee 29 12489 Berlin GERMANY www.eagleyard.com info@eagleyard.com fon +49.30.6392 4520

This data sheet is subject to change without notice. © eagleyard Photonics

 0° ... 50° C

Measurement Conditions / Comments

 $R_1 \,/\, R_2 = e^{\ \beta \, (1/T_1 \,-\, 1/T_2)} \,$ at $T_{LD} =$

 $1/T = A + B(\ln R) + C(\ln R)^3$ T: temperature in Kelvin R: resistance at T in Ohm

 $T_{LD} = 25^{\circ} C$



2020-11-11



Measurement Conditions / Comments

 $U_R = 5 V$

Measurement Conditions / Comments				
$P_{opt} = 40 \text{ mW}, \Delta T = 20 \text{ K}$				
$P_{opt} = 40 \text{ mW}, \Delta T = 20 \text{ K}$				
$P_{opt} = 40 \text{ mW}, \Delta T = 20 \text{ K}$				
$P_{opt} = 40 \text{ mW}, \Delta T = Tcase - TLD $				



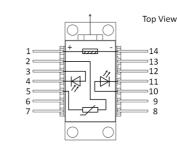
Revision 0.94

2020-11-11

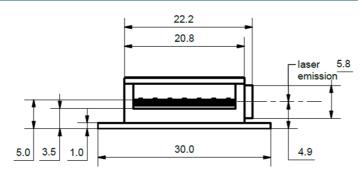
SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

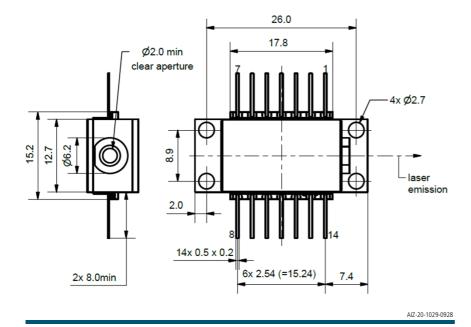
Pin Assignment

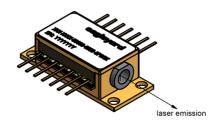
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor	13	Case
3	Photodiode (Anode)	12	not connected
4	Photodiode (Cathode)	11	Laser Diode (Cathode)
5	Thermistor	10	Laser Diode (Anode)
6	not connected	9	not connected
7	not connected	8	not connected



Package Drawings







Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

See instruction manual on www.eagleyard.com

eagleyard Photonics GmbH Rudower Chaussee 29 12489 Berlin GERMANY www.eagleyard.com info@eagleyard.com fon +49.30.6392 4520

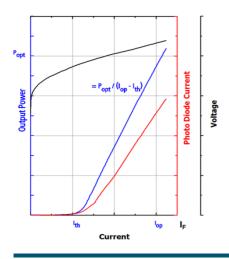
This data sheet is subject to change without notice. © eagleyard Photonics

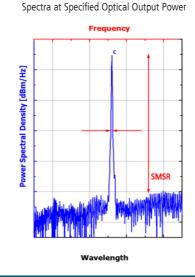
Revision 0.94

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

Typical Measurement Results

Output Power vs. Current





Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

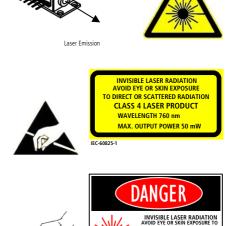
The DFB laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

eagleyard Photonics GmbH Rudower Chaussee 29 12489 Berlin GERMANY www.eagleyard.com info@eagleyard.com fon +49.30.6392 4520

This data sheet is subject to change without notice. © eagleyard Photonics



DIRECT OR SCATTERED RADIATION GaAs SEMICONDUCTOR LASER DIODE IO MW MAX OUTPUT AT 760 nn CLASS IV LASER PRODUCT th 21 CFR 1040.10 and 1040.40



